



# **MMBT4401T**

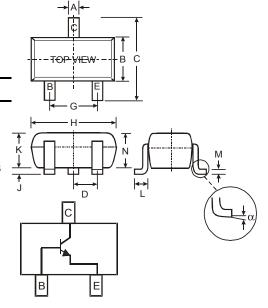
## NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

#### **Features**

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMBT4403T)
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

#### **Mechanical Data**

- Case: SOT-523
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: 2X, See Page 4
- Ordering & Date Code Information: See Page 4
- Weight: 0.002 grams (approximate)



SOT-523									
Dim	Min	Max	Тур						
Α	0.15	0.30	0.22						
В	0.75	0.85	0.80						
С	1.45	1.75	1.60						
D	_	_	0.50						
G	0.90	1.10	1.00						
Н	1.50	1.70	1.60						
J	0.00	0.10	0.05						
K	0.60	0.80	0.75						
L	<b>L</b> 0.10 0.3		0.22						
М	0.10	0.20	0.12						
N	0.45	0.65	0.50						
α	0°	8°							
All Dimensions in mm									

## **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage		V <sub>CBO</sub>	60	V
Collector-Emitter Voltage		V <sub>CEO</sub>	40	V
Emitter-Base Voltage		V <sub>EBO</sub>	6.0	V
Collector Current – Continuous	(Note 1)	Ic	600	mA
Power Dissipation	(Note 1)	P <sub>d</sub>	150	mW
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ hetaJA}$	833	°C/W
Operating and Storage Temperature Range		T <sub>i</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

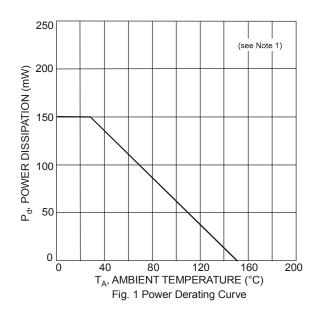
- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead
- 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
- 4. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

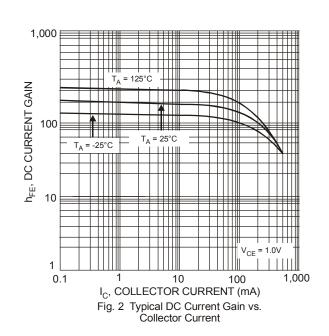


## **Electrical Characteristics** @TA = 25°C unless otherwise specified

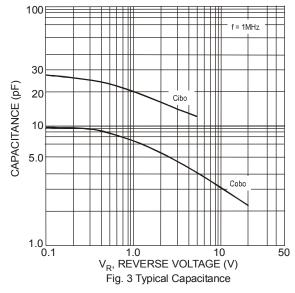
Characteristic	Symbol	Symbol Min		Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)						
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	60	_	V	$I_C = 100 \mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	40	_	V	$I_C = 1.0 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	6.0	_	V	$I_E = 100 \mu A, I_C = 0$	
Collector Cutoff Current	I <sub>CEX</sub>	_	100	nA	V <sub>CE</sub> = 35V, V <sub>EB(OFF)</sub> = 0.4V	
Base Cutoff Current	I <sub>BL</sub>	_	100	nA	V <sub>CE</sub> = 35V, V <sub>EB(OFF)</sub> = 0.4V	
ON CHARACTERISTICS (Note 5)						
DC Current Gain	h <sub>FE</sub>	20 40 80 100 40		_	$\begin{split} I_{C} &= 100 \mu A, \ V_{CE} = 1.0 V \\ I_{C} &= 1.0 m A, \ V_{CE} = 1.0 V \\ I_{C} &= 10 m A, \ V_{CE} = 1.0 V \\ I_{C} &= 150 m A, \ V_{CE} = 1.0 V \\ I_{C} &= 500 m A, \ V_{CE} = 2.0 V \end{split}$	
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	0.40 0.75	V	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA	
Base-Emitter Saturation Voltage		0.75	0.95 1.2	V	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA	
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C <sub>obo</sub>	_	6.5	pF	$V_{CB} = 5.0V$ , $f = 1.0MHz$ , $I_{E} = 0$	
Input Capacitance	C <sub>ibo</sub>	_	30	pF	$V_{EB} = 0.5V$ , $f = 1.0MHz$ , $I_C = 0$	
Input Impedance	h <sub>ie</sub>	1.0	15	kΩ		
Voltage Feedback Ratio	h <sub>re</sub>	0.1	8.0	x 10 <sup>-4</sup>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 1.0mA,	
Small Signal Current Gain	h <sub>fe</sub>	40	500	_	f = 1.0kHz	
Output Admittance	h <sub>oe</sub>	1.0	30	μS		
Current Gain-Bandwidth Product	f <sub>T</sub>	250	_	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 20mA, f = 100MHz	
SWITCHING CHARACTERISTICS				_		
Delay Time	t <sub>d</sub>		15	ns	V <sub>CC</sub> = 30V, I <sub>C</sub> = 150mA,	
Rise Time	t <sub>r</sub>	_	20	ns	$V_{BE(off)} = 2.0V, I_{B1} = 15mA$	
Storage Time	t <sub>s</sub>		225	ns	V <sub>CC</sub> = 30V, I <sub>C</sub> = 150mA,	
Fall Time	t <sub>f</sub>	_	30	ns	$I_{B1} = I_{B2} = 15mA$	

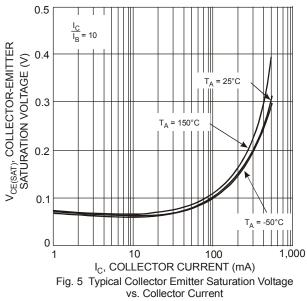
Notes: 5. Short duration pulse test used to minimize self-heating effect.

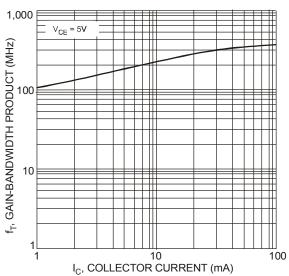


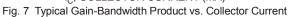


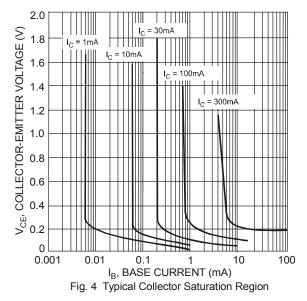












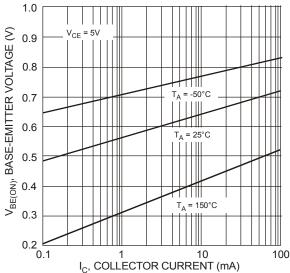


Fig. 6 Typical Base-Emitter Voltage vs. Collector Current

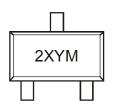


#### Ordering Information (Note 6)

Device		Packaging	Shipping		
MMBT4401T-7-	F	SOT-523	3000/Tape & Reel		

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



2X = Product Type Marking Code YM = Date Code Marking Y = Year (ex: T = 2006) M = Month (ex: 9 = September)

Date Code Key

Year	2002	2003	2004	2005	200	06 20	007	2008	2009	2010	2011	2012
Code	N	Р	R	S	Т		U	V	W	Х	Υ	Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Au	g Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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